# NSN 5961-01-137-9154

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### **Inclosure Material:**

Plastic

**Overall Length:** 

0.580 inches

## **Overall Height:**

0.140 inches

### **Overall Width:**

0.380 inches

## **Mounting Facility Quantity:**

1

### Internal Configuration:

Junction contact

## Joint Electronic Device Engineering Council/jedec/case Outline Designation:

To-220b

### **Mounting Method:**

## Unthreaded hole

Semiconductor Material:

Silicon

## Voltage Rating In Volts Per Characteristic:

50.0 breakdown voltage, collector-to-base, emitter open and 50.0 breakdown voltage, collector-to-emitter, base open and 5.0 breakdown

voltage, emitter-to-base, collector open

### **Current Rating Per Characteristic:**

Between 5.00 amperes source cutoff current and 15.00 amperes source cutoff current

### **Power Rating Per Characteristic:**

30.0 watts small-signal input power, common-collector

### Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

### **Special Features:**

Junction pattern arrangement: npn

### Terminal Type And Quantity:

3 pin

### **Specification Data:**

80131-release6488 professional/industrial association specification

#### Shelf Life:

N/a

## Unit Of Measure:

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### Demilitarization:

No

### Fiig:

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